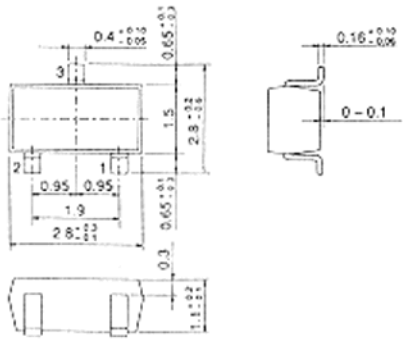
HITACHI

2SC4196

SILICON NPN EPITAXIAL

UHF LOCAL OSCILLATOR



1. Emitter
2. Base
3. Collector

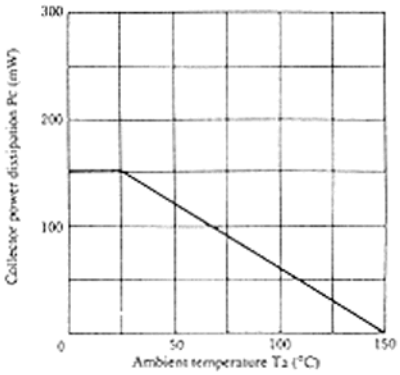
(Dimensions in mm)

(MPAK)

■ ABSOLUTE MAXIMUM RATINGS (Ta=25°C)

Item	Symbol	2SC4196	Unit
Collector to base voltage	V_{CBO}	25	V
Collector to emitter voltage	V_{CEO}	15	V
Emitter to base voltage	V_{EBO}	3	V
Collector current	I_C	50	mA
Collector power dissipation	P_C	150	mW
Junction temperature	T_j	150	°C
Storage temperature	T_{stg}	−55 to +150	°C

MAXIMUM COLLECTOR DISSIPATION CURVE



■ ELECTRICAL CHARACTERISTICS (Ta=25°C)

Item	Symbol	Test Condition	min.	typ.	max.	Unit
Collector to base breakdown voltage	$V_{(BR)CBO}$	I_C = 10μA, I_E = 0	25	—	—	V
Collector cutoff current	I_{CBO}	V_{CB} =15V, I_E = 0	—	—	0.3	μA
	I_{CEO}	V_{CE} =15V, R_{BE} = ∞	—	—	10	μA
Emitter cutoff current	I_{EBO}	V_{EB} =3V, I_C = 0	—	—	1.0	μA
Collector to emitter saturation voltage	$V_{CE(sat)}$	I_C =20mA, I_B = 4mA	—	—	0.3	V
DC current transfer ratio	h_{FE}	V_{CE} = 5V, I_C = 5mA	50	—	180	
Collector output capacitance	C_{ob}	V_{CB} = 10V, I_E = 0, f = 1MHz	—	0.7	1.0	pF
Gain bandwidth product	f_T	V_{CE} = 5V, I_C = 20mA	1.8	2.4	—	GHz
Oscillating output voltage	V_{OSC}	V_{CC} =5V, I_C = 5mA, f = 930MHz	—	200	—	mV

* Marking is "Q1-".

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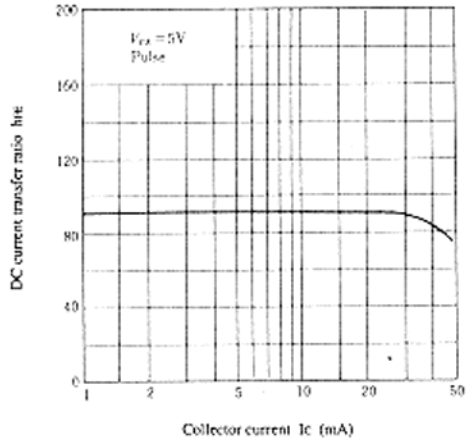
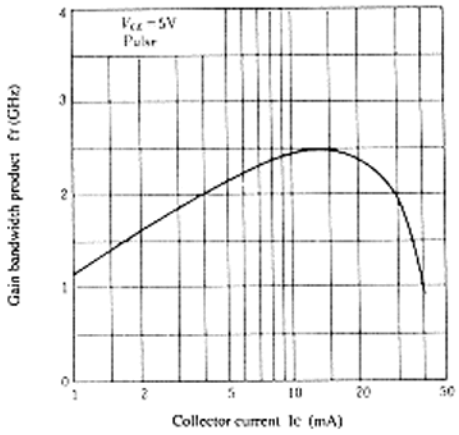
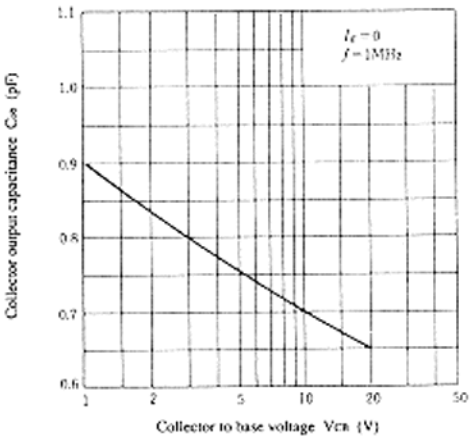
DC CURRENT TRANSFER RATIO VS. COLLECTOR CURRENT



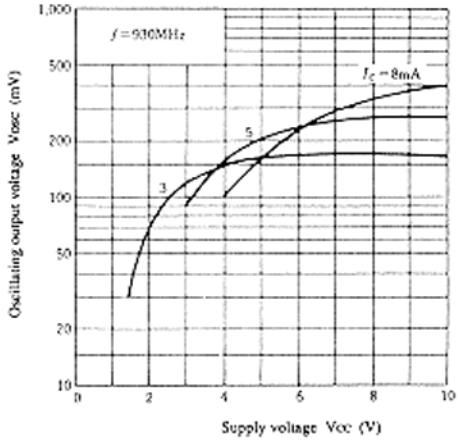
GAIN BANDWIDTH PRODUCT VS. COLLECTOR CURRENT



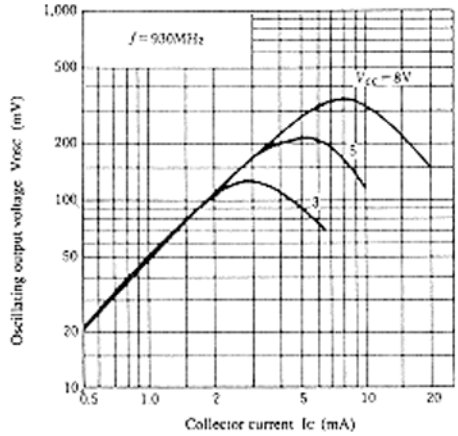
COLLECTOR OUTPUT CAPACITANCE VS. COLLECTOR TO BASE VOLTAGE



OSCILLATING OUTPUT VOLTAGE VS. SUPPLY VOLTAGE

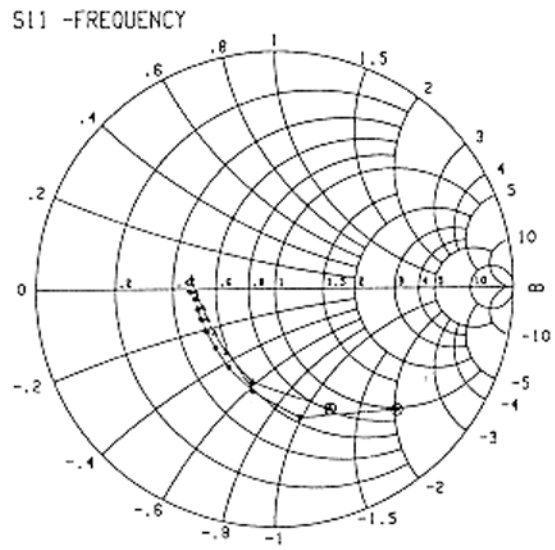


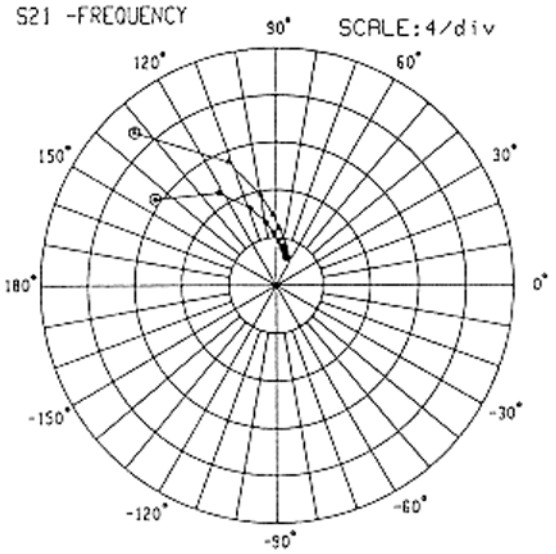
OSCILLATING OUTPUT VOLTAGE VS. COLLECTOR CURRENT

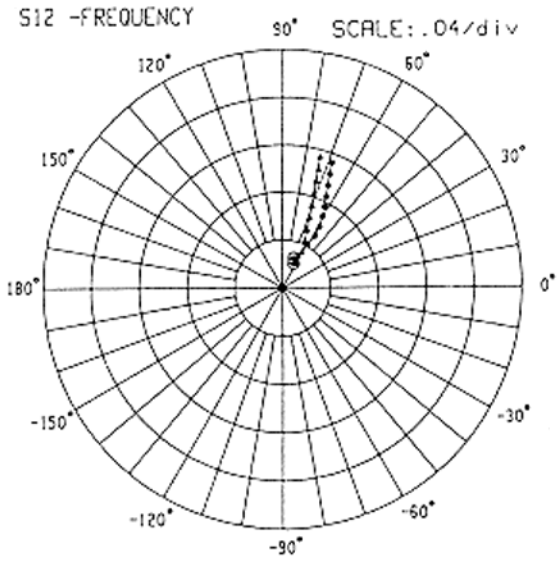


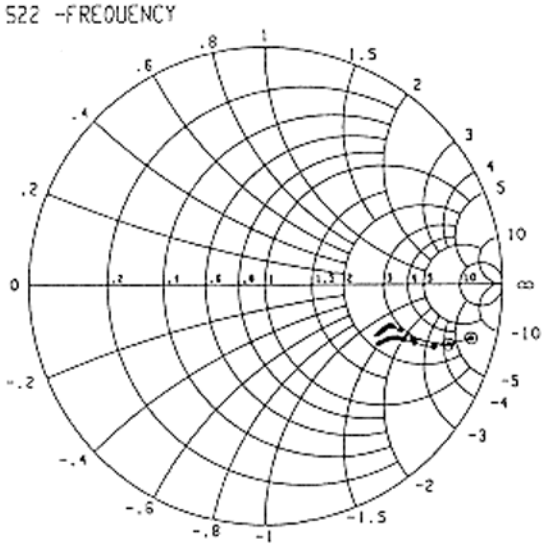
■ **S PARAMETERS** (Emitter Common)

Test Condition: V_{CE} = 5V, 100MHz to 1000MHz (100MHz STEP), Zo = 50Ω
I_C = 5mA
I_C = 10mA









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■ S PARAMETERS (Emitter Common)

Test Condition: V_{CE}=5V, I_C=5mA, Z_O=50Ω

FREQ.	S11		S21		S12		S22	
(MHz)	MAG.	ANG.	MAG.	ANG.	MAG.	ANG.	MAG.	ANG.
100	0.718	−44.8	12.498	144.9	0.026	68.8	0.895	−14.6
200	0.549	−78.8	9.123	122.0	0.042	59.3	0.756	−20.3
300	0.439	−102.0	6.788	108.4	0.051	57.6	0.671	−21.3
400	0.381	−120.8	5.348	99.3	0.060	58.5	0.626	−21.5
500	0.351	−135.5	4.396	92.4	0.068	60.6	0.600	−21.8
600	0.340	−148.2	3.732	86.7	0.076	62.5	0.582	−22.5
700	0.337	−157.8	3.240	81.7	0.085	64.3	0.569	−23.3
800	0.337	−165.2	2.875	77.3	0.094	66.0	0.558	−24.4
900	0.343	−173.1	2.575	73.4	0.103	67.3	0.547	−25.8
1000	0.359	−177.9	2.355	70.0	0.112	68.4	0.538	−27.2

Test Condition: V_{CE}=5V, I_C=10mA, Z_O=50Ω

FREQ.	S11		S21		S12		S22	
(MHz)	MAG.	ANG.	MAG.	ANG.	MAG.	ANG.	MAG.	ANG.
100	0.553	−65.2	17.540	133.2	0.022	64.8	0.809	−18.0
200	0.401	−103.4	11.066	111.3	0.033	61.3	0.659	−20.0
300	0.337	−127.4	7.723	99.9	0.043	63.9	0.598	−18.6
400	0.314	−143.9	5.939	92.5	0.052	66.3	0.570	−18.1
500	0.313	−155.7	4.816	86.7	0.063	68.6	0.555	−18.2
600	0.314	−165.5	4.052	81.8	0.073	70.1	0.545	−18.9
700	0.327	−172.2	3.496	77.6	0.083	71.4	0.536	−19.9
800	0.335	−177.7	3.090	73.8	0.093	72.4	0.530	−21.0
900	0.349	176.8	2.753	70.1	0.103	73.0	0.523	−22.4
1000	0.354	172.8	2.515	67.0	0.113	74.0	0.516	−24.0

■ Y PARAMETERS (Emitter Common)

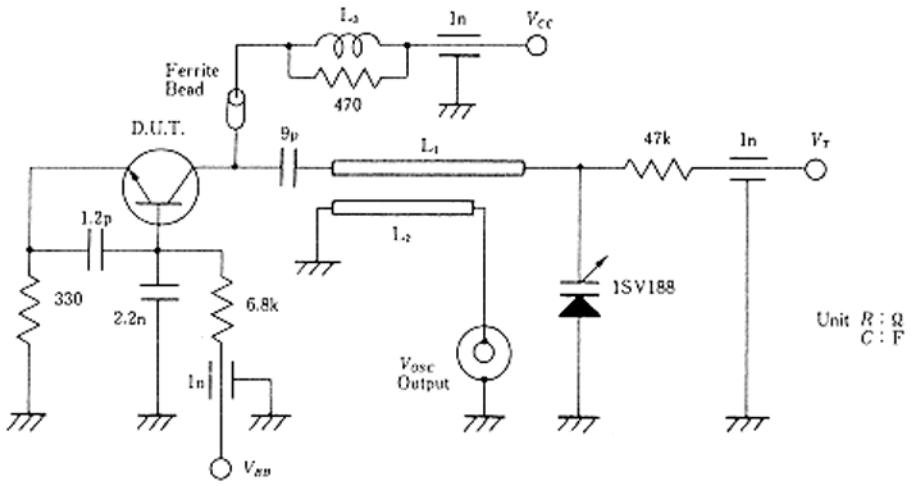
Test Condition: V_{CE}=5V, I_C=5mA

FREQ.	Yie (mS)		Yfe (mS)		Yre (mS)		Yoe (mS)	
(MHz)	REAL	IMAG.	REAL	IMAG.	REAL	IMAG.	REAL	IMAG.
100	3.035	5.491	152.256	−40.168	−0.005	−0.334	0.048	0.613
200	6.463	10.003	131.145	−71.318	−0.015	−0.679	0.100	1.238
300	10.768	12.356	103.025	−90.187	−0.036	−1.034	0.191	1.804
400	15.089	13.186	77.334	−98.666	−0.065	−1.397	0.232	2.386
500	18.776	12.837	55.039	−99.977	−0.090	−1.767	0.270	2.947
600	22.098	11.913	37.290	−98.247	−0.128	−2.134	0.347	3.555
700	24.568	10.731	22.802	−93.799	−0.163	−2.515	0.417	4.133
800	26.291	9.416	11.686	−88.266	−0.193	−2.890	0.516	4.703
900	28.112	7.683	2.225	−82.972	−0.260	−3.305	0.614	5.354
1000	29.685	6.751	−3.931	−78.720	−0.291	−3.746	0.629	5.908

Test Condition: V_{CE}=5V, I_C=10mA

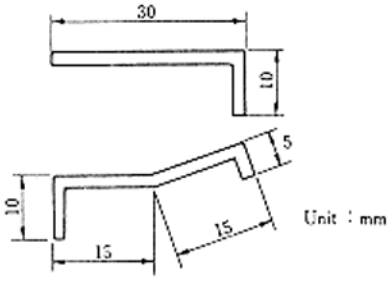
FREQ.	Yie (mS)		Yfe (mS)		Yre (mS)		Yoe (mS)	
(MHz)	REAL	IMAG.	REAL	IMAG.	REAL	IMAG.	REAL	IMAG.
100	5.903	7.347	243.307	−103.091	−0.008	−0.338	0.026	0.591
200	11.583	10.820	168.225	−150.806	−0.022	−0.682	0.128	1.254
300	16.546	10.993	103.210	−155.623	−0.045	−1.041	0.216	1.797
400	20.055	10.038	61.965	−145.393	−0.074	−1.387	0.320	2.394
500	22.491	8.943	35.421	−131.365	−0.093	−1.766	0.316	2.917
600	24.417	7.556	16.762	−118.513	−0.133	−2.138	0.378	3.544
700	26.086	6.620	5.096	−107.291	−0.155	−2.531	0.424	4.086
800	27.193	5.569	−3.874	−97.359	−0.185	−2.923	0.469	4.659
900	28.543	4.340	−11.095	−88.952	−0.248	−3.349	0.563	5.307
1000	28.955	3.253	−15.953	−81.466	−0.270	−3.737	0.650	5.861

■ Vosc Test Circuit



L1: ϕ0.8mm Enameled Copper Wire.

L2: ϕ0.8mm Enameled Copper Wire.



L3: Inside dia 3mm, ϕ0.3mm Enameled Copper Wire 10 Turns.